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June 2014

# FSA2270T Low-Voltage, Dual-SPDT (0.4 $\Omega$ ) Analog Switch with Negative Swing Audio Capability

#### **Features**

- 0.4 Ω Typical On Resistance (R<sub>ON</sub>) for +3.0 V Supply
- 0.25 Ω Maximum R<sub>ON</sub> Flatness for +3.0 V Supply
- -3 db Bandwidth: > 50 MHz
- Low-I<sub>CCT</sub> Current Over Expanded Control Input Range
- Packaged in 10-Lead UMLP
- Power-Off Protection on Common Ports
- Broad V<sub>CC</sub> Operating Range: 1.65 to 4.3 V
- Noise Immunity Termination Resistors
- Low Electrostatic Discharge (ESD)
  - Human Body Model (JEDEC: JESD22-A114)

Power to GND
I/O to GND
All other pins
16 kV
11 kV
8 kV

- Charged Device Model (JEDEC: JESD22-A101)

## **Applications**

- Cell Phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-Top Box

#### **IMPORTANT NOTE:**

For additional information, please contact analogswitch@fairchildsemi.com.

#### Description

The FSA2270T is a high-performance, dual Single-Pole Double-Throw (SPDT) analog switch with negative swing audio capability. The FSA2270T features ultra-low  $R_{\text{ON}}$  of 0.4  $\Omega$  (typical) at 3.0 V V $_{\text{CC}}$ . The FSA2270T operates over a wide V $_{\text{CC}}$  range of 1.65 V to 4.3 V, is fabricated with sub-micron CMOS technology to achieve fast switching speeds, and is designed for break-before-make operation. The select input is TTL-level compatible.

The FSA2270T features very low quiescent current even when the control voltage is lower than the  $V_{\rm CC}$  supply. This feature suits mobile handset applications by allowing direct interface with baseband processor general-purpose I/Os with minimal battery consumption.

The FSA2270T includes termination resistors that improve noise immunity during overshoot excursions, off-isolation coupling, or "pop-minimization."

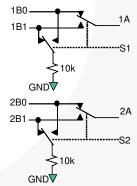


Figure 1. Analog Symbol

## **Ordering Information**

Part Number	Top Mark	Package Description
FSA2270TUMX	НК	10-Lead, Quad Ultrathin Molded Leadless Package (UMLP), 1.4 x 1.8 mm, 0.4 mm Pitch

## **Pin Configuration**

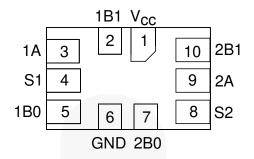


Figure 2. 10-Pin UMLP (Top Through View)

## **Pin Descriptions**

Pin#	Name	Description
1	V <sub>CC</sub>	Supply Voltage
3, 9	1A, 2A	Data Points
4, 8	S1, S2	Switch Select Pins
5, 7	1B0, 2B0	Data Ports
6	GND	Ground
2, 10	1B1, 2B1	Data Ports

## **Truth Table**

Control Input, Sn	Function	
LOW Logic Level	nB0 connected to nA; nB1 terminated to GND	
HIGH Logic Level	nB1 connected to nA; nB0 terminated to GND	

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. Functional operation above the recommended operating conditions is not implied. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. Absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Units
V <sub>CC</sub>	Supply Voltage	Supply Voltage		5.5	V
V <sub>SW</sub>	Switch I/O Voltage <sup>(1)</sup>	1B0, 1B1, 2B0, 2B1, 1A, 2A Pins	V <sub>CC</sub> - 4.3	V <sub>CC</sub> + 0.3	V
V <sub>CNTRL</sub>	Control Input Voltage <sup>(1)</sup>	S1, S2	-0.5	V <sub>CC</sub> + 0.3	
I <sub>IK</sub>	Input Clamp Diode Current			-50	mA
I <sub>SW</sub>	Switch I/O Current (Continu	Switch I/O Current (Continuous)		350	mA
I <sub>SWPEAK</sub>	Peak Switch Current (Pulsed at 1 ms Duration, <10% Duty Cycle)			500	mA
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
$T_J$	Maximum Junction Temperature			+150	°C
TL	Lead Temperature Solderin	g, 10 Seconds		+260	°C
//		Power to GND	\.	16	kV
ESD	Human Body Model, JEDEC: JESD22-A114	I/O to GND		11	kV
ESD	CESES. GEOBLE ATT	All Other Pins		8	kV
	Charged Device Model, JEI	DEC: JESD22-C101		2	kV

#### Note:

1. Input and output negative ratings may be exceeded if input and output diode current ratings are observed.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V <sub>CC</sub>	Supply Voltage	1.65	4.30	V
V <sub>S1, S2</sub>	Control Input Voltage	0	$V_{CC}$	٧
$V_{SW}$	Switch I/O Voltage	V <sub>CC</sub> - 4.3	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

## **DC Electrical Characteristics**

All typical values are for  $V_{\text{CC}}$ =3.3 V at  $T_{\text{A}}$ =25°C unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>cc</sub> (V)	T <sub>A</sub> =+25°C			T <sub>A</sub> =-40 to +85°C		Units
				Min.	Тур.	Max.	Min.	Max.	
			3.60 to 4.30				1.7		
	Lee IVellee IPele		2.70 to 3.60				1.5		
$V_{IH}$	Input Voltage High		2.30 to 2.70				1.4		V
			1.65 to 1.95				0.9		
			3.60 to 4.30					0.7	V
\/	Innut Valtaga I au		2.70 to 3.60					0.5	
$V_{IL}$	Input Voltage Low		2.30 to 2.70					0.4	V
			1.65 to 1.95					0.4	
I <sub>IN</sub>	Control Input Leakage (S1, S2)	V <sub>IN</sub> =0 to V <sub>CC</sub>	1.65 to 4.30				-0.5	0.5	μΑ
I <sub>A(ON)</sub>	On Leakage Current of Port nA	nA=0.5 V, $V_{\rm CC}$ -0.5 V nB0 or nB1= $V_{\rm CC}$ -0.5 V, 0.5 V, or Floating Figure 5	1.95 to 4.30				-1	1	μΑ
l <sub>OFF</sub>	Power-Off Leakage Current (Common Port Only 1A, 2A)	Common Port (1A, 2A), V <sub>IN</sub> =0 V to 4.3 V, V <sub>CC</sub> =0 V nB0, nB1=0 V or Floating	0				-45	45	μΑ
		I <sub>ON</sub> =100 mA, nB0 or nB1=0.7 V, 3.6 V, 4.3 V Figure 3	4.30		0.30				
		I <sub>ON</sub> =100 mA, nB0 or nB1=0.7 V, 3.6 V, 4.3 V Figure 3	3.00		0.40			0.80	
R <sub>ON</sub>	Switch On Resistance <sup>(2,5)</sup>	I <sub>ON</sub> =100 mA, nB0 or nB1=0 V, 0.7 V, 1.6 V, 2.3 V Figure 3	2.30		0.52				Ω
		I <sub>ON</sub> =100 mA, nB0 or nB1=0 V, 0.7 V, 1.65 V Figure 3	1.65		1.00				
			4.30		0.04			0.13	
A.D.	On Resistance Matching	I <sub>ON</sub> =100 mA, nB0 or	3.00		0.06			0.13	_
$\Delta R_{ON}$	Between Channels <sup>(3)</sup>	nB1=0.7 V	2.30		0.12				Ω
			1.65		1.00				
			4.30					0.25	
D	On Resistance	I <sub>OUT</sub> =100 mA, nB0 or	3.00					0.25	Ω
$R_{FLAT(ON)}$	Flatness <sup>(4)</sup>	nB1=0 V to V <sub>CC</sub>	2.30		0.5				72
			1.65		0.6				
R <sub>TERM</sub>	Internal Termination Resistors <sup>(5)</sup>				10				kΩ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =0 V or V <sub>CC</sub> , I <sub>OUT</sub> =0 mA	4.30	-100		100	-500	500	nA
		Input at 2.6 V			3.0			10.0	_
$I_{CCT}$	Increase in I <sub>CC</sub> per Input	Input at 1.8 V	4.30		7.0			15.0	μΑ

#### Notes:

- 2. On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.
- 3.  $\Delta R_{ON} = R_{ONmax} R_{ONmin}$  measured at identical  $V_{CC}$ , temperature, and voltage.
- 4. Flatness is defined as the difference between the maximum and minimum value of on resistance (R<sub>ON</sub>) over the specified range of conditions.
- 5. Guaranteed by characterization, not production tested.

## **AC Electrical Characteristics**

All typical value are for  $V_{\text{CC}}\!\!=\!\!3.3~V$  at  $T_{A}\!\!=\!\!25^{\circ}\!C$  unless otherwise specified.

Ob. a.l.	Symbol Parameter Conditions		V 00	-	T <sub>A</sub> =+25º	С	T <sub>A</sub> =-40	to +85°C	11-24-	F:
Symbol			V <sub>CC</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Units	Figure
			3.60 to 4.30			60	15	65		
	Turn-On Time	nB0 or nB1=1.5 V,	2.70 to 3.60			65	15	70	ns	Figure 6
t <sub>ON</sub>	Tuni-On Time	$R_L=50 \Omega, C_L=35 pF$	2.30 to 2.70			80	15	85	115	Figure 7
			1.65 to 1.95		100					
			3.60 to 4.30			55	5	60		
t	Turn-Off Time	nB0 or nB1=1.5 V,	2.70 to 3.60			60	5	65	ns	Figure 6 Figure 7
t <sub>OFF</sub>	Tuni-On Time	$R_L=50 \Omega, C_L=35 pF$	2.30 to 2.70			65	5	70	115	
			1.65 to 1.95		65					
			3.60 to 4.30		3		1		- ns	Figure 8
+	Break-Before-	nB0 or nB1=1.5 V,	2.70 to 3.60		5		2			
t <sub>BBM</sub>	Make Time	$R_L=50 \Omega, C_L=35 pF$	2.30 to 2.70		10		2			
			1.65 to 1.95		15		2			
Q	Charge Injection	$C_L$ =1.0 nF, $V_S$ =0 V, $R_S$ =0 $\Omega$	1.65 to 4.30		25				рС	Figure 12
OIRR	Off Isolation	f=100 kHz, R <sub>L</sub> =50 Ω, C <sub>L</sub> =0 pF	1.65 to 4.30		-70				dB	Figure 10
Xtalk	Crosstalk	f=100 kHz, R <sub>L</sub> =50 Ω, C <sub>L</sub> =0 pF	1.65 to 4.30		-70				dB	Figure 11
BW	-3 db Bandwidth	$R_L=50 \Omega$ , $C_L=0 pF$	1.65 to 4.30		>50				MHz	Figure 9
THD	Total Harmonic Distortion	f=20 Hz to 20 kHz, RL=32 $\Omega$ , VIN=2 Vpp VBIAS=0 V	1.65 to 4.30		.06				%	Figure 15

## Capacitance

Symbol Parameter		Parameter Conditions V <sub>CC</sub> (V)		Т	_=+25ºC	Units	Figure		
Syllibol	Farameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Uiiiis	Figure	
C <sub>IN</sub>	Control Pin Input Capacitance	f=1 MHz	0		2.5		pF	Figure 13	
C <sub>OFF</sub>	B Port Off Capacitance	f=1 MHz	3.3		30		pF	Figure 13	
Con	A Port On Capacitance	f=1 MHz	3.3		120		pF	Figure 14	

## **Test Diagrams**

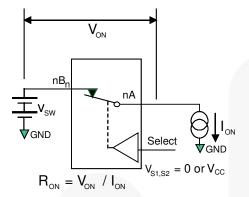
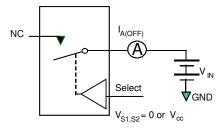


Figure 3. On Resistance



Each switch port is tested separately.

Figure 4. Off Leakage

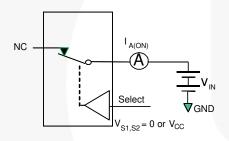


Figure 5. On Leakage

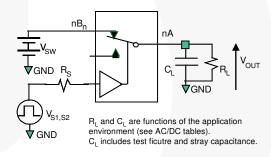


Figure 6. Test Circuit Load

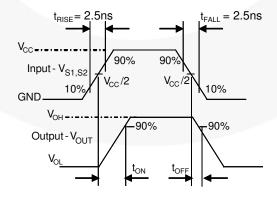


Figure 7. Turn-On / Turn-Off Waveforms

## Test Diagrams (Continued)

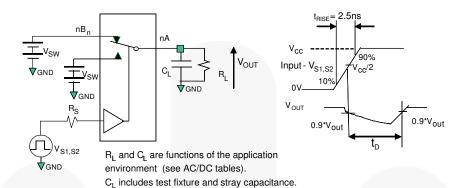


Figure 8. Break-Before-Make Interval Timing

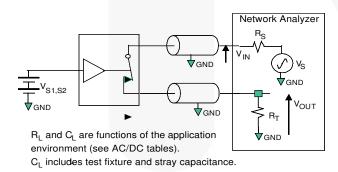


Figure 9. Bandwidth

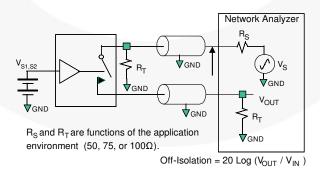


Figure 10. Channel Off Isolation

## Test Diagrams (Continued)

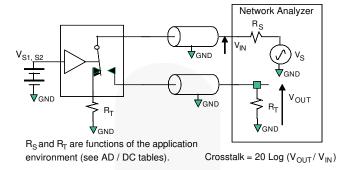


Figure 11. Adjacent Channel Crosstalk

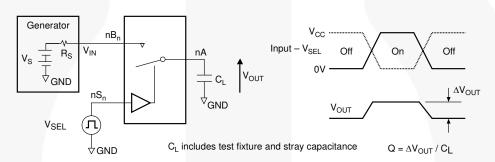


Figure 12. Charge Injection Test



Figure 13. Channel Off Capacitance

Figure 14. Channel On Capacitance

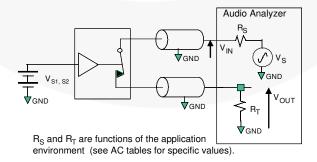


Figure 15. Total Harmonic Distortion

## **Physical Dimensions**

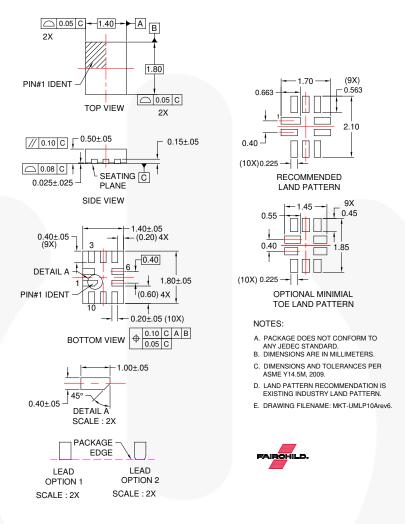


Figure 16. 10-Lead, Quad Ultrathin Molded Leadless Package (UMLP)

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Table 1. Nominal Values

JEDEC Symbol	Description	Nominal Values (mm)
А	Overall Height	0.5
A1	Package Standoff	0.026
A3	Lead Thickness	0.152
b	Lead Width	0.2
L	Lead Length	0.4
е	Lead Pitch	0.4
D	Body Length (Y)	1.8
E	Body Width (X)	1.4





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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.					
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